

## 1 Product profile

### 1.1 General description

Planar PIN diode in a SOD882D leadless ultra small plastic SMD package.

#### 1.2 Features and benefits

- High voltage, current controlled RF resistor for RF attenuators and switches
- · Low diode capacitance
- · Low forward resistance
- · Very low series inductance
- For applications up to 3 GHz
- AEC-Q101 qualified

### 1.3 Applications

· RF attenuators and switches



# 2 Pinning information

Table 1. Discrete pinning

Pin	Description	Simplified outline	Symbol
1	cathode [		1.4
2	anode	Transparent top view	sym006

<sup>[1]</sup> The marking bar indicates the cathode.

# 3 Ordering information

**Table 2. Ordering information** 

Type number	Package			
	Name	Description	Version	
BAP64LX	DFN1006D-2	leadless ultra small plastic package; 2 terminals; body 1 x 0.6 x 0.4 mm	SOD882D	

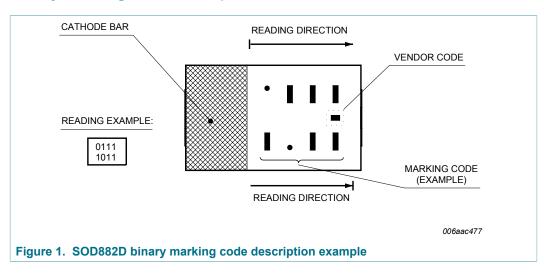
# 4 Marking

Table 3. Marking codes

Type number	Marking code <sup>[1]</sup>
BAP64LX	1111 1111

<sup>[1]</sup> For SOD882D binary marking code description, see  $\underline{\text{Figure 1}}$ .

## 4.1 Binary marking code description



BAP64LX

# 5 Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_R$	reverse voltage		-	60	V
I <sub>F</sub>	forward current		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> = 90 °C	-	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-65	+150	°C

## 6 Thermal characteristics

**Table 5. Thermal characteristics** 

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		56	K/W

## 7 Characteristics

### **Table 6. Characteristics**

 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 100 mA	-	0.95	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 60 V	-	-	100	nA
$C_{d}$	diode capacitance	see Figure 2; f = 1 MHz;				
		V <sub>R</sub> = 0 V	-	0.48	-	pF
		V <sub>R</sub> = 1 V	-	0.34	-	pF
		V <sub>R</sub> = 20 V	-	0.17	0.30	pF
r <sub>D</sub>	diode forward resistance	see Figure 3; f = 100 MHz;				
		I <sub>F</sub> = 0.5 mA	-	31	50	Ω
		I <sub>F</sub> = 1 mA	-	16	26	Ω
		I <sub>F</sub> = 10 mA	-	2.6	4.4	Ω
		I <sub>F</sub> = 100 mA	-	0.9	1.5	Ω
ISL	isolation	see Figure 4; V <sub>R</sub> = 0 V;				
		f = 900 MHz	-	22	-	dB
		f = 1800 MHz	-	16	-	dB
		f = 2450 MHz	-	14	-	dB
L <sub>ins</sub>	insertion loss	see <u>Figure 5</u> ; I <sub>F</sub> = 0.5 mA;				
		f = 900 MHz	-	2.15	-	dB
		f = 1800 MHz	-	2.13	-	dB
		f = 2450 MHz	-	2.14	-	dB
L <sub>ins</sub>	insertion loss	see <u>Figure 5</u> ; I <sub>F</sub> = 1 mA;				
		f = 900 MHz	-	1.21	-	dB
		f = 1800 MHz	-	1.21	-	dB
		f = 2450 MHz	-	1.22	-	dB
L <sub>ins</sub>	insertion loss	see Figure 5; I <sub>F</sub> = 10 mA;				
		f = 900 MHz	-	0.22	-	dB
		f = 1800 MHz	-	0.23	-	dB
		f = 2450 MHz	-	0.24	-	dB
L <sub>ins</sub>	insertion loss	see <u>Figure 5</u> ; I <sub>F</sub> = 100 mA;				
		f = 900 MHz	-	0.09	-	dB
		f = 1800 MHz	-	0.1	-	dB
		f = 2450 MHz	-	0.11	-	dB
T <sub>L</sub>	charge carrier life time	when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 6 mA; R <sub>L</sub> = 100 $\Omega$ ; measured at I <sub>R</sub> = 3 mA	-	1.0	-	μs

10<sup>2</sup>

I<sub>F</sub> (mA)

001aag640

2500 3000 f (MHz)

#### Silicon PIN diode

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
L <sub>S</sub>	series inductance	I <sub>F</sub> = 100 mA; f = 100 MHz	-	0.4	-	nH

10<sup>2</sup>

10

10<sup>-1</sup>

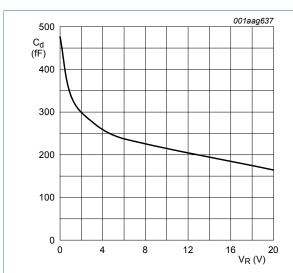
10<sup>-1</sup>

 $f = 100 \text{ MHz}; T_i = 25 ^{\circ}\text{C}.$ 

current; typical values

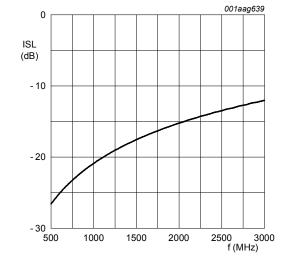
 $r_D$  $(\Omega)$ 

### 7.1 Graphics



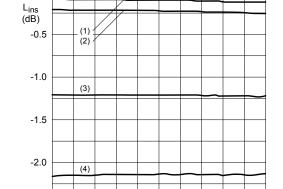
f = 1 MHz;  $T_i = 25 °C$ .

Figure 2. Diode capacitance as a function of reverse voltage; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

Diode zero biased and inserted in series with a 50  $\Omega$  stripline circuit



1500

2000

Figure 3. Forward resistance as a function of forward

T<sub>amb</sub> = 25 °C

-2.5

500

1000

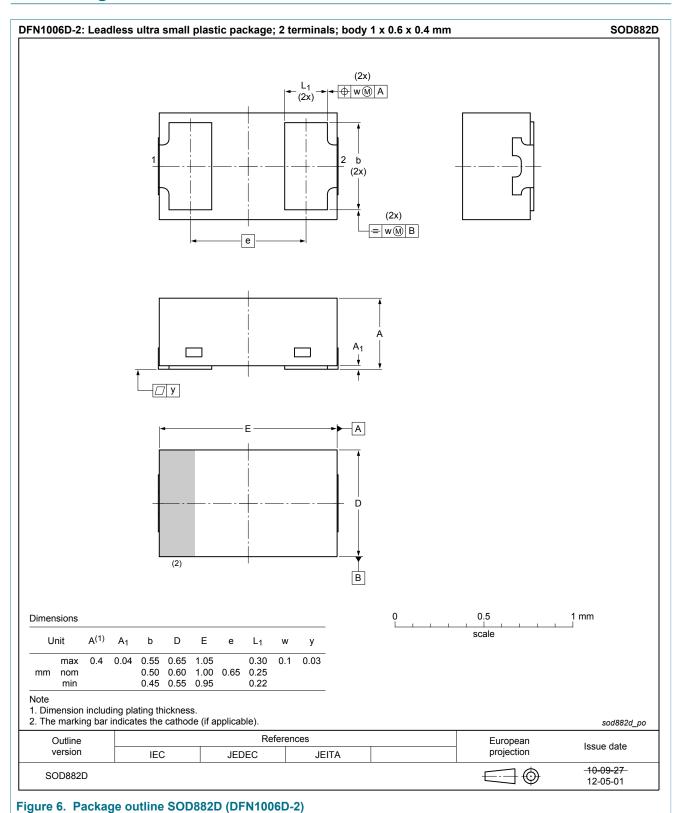
- 1.  $I_F = 100 \text{ mA}$
- 2.  $I_F = 10 \text{ mA}$
- 3.  $I_F = 1 \text{ mA}$
- 4.  $I_F = 0.5 \text{ mA}$

Diode inserted in series with a 50  $\Omega$  stripline circuit and biased via the analyzer Tee network

Figure 5. >Insertion loss of the diode as a function of frequency; typical values



# 8 Package outline



## 9 Abbreviations

Table 7. Abbreviations

Acronym	Description
AQL	acceptable quality level
PIN	P-type, intrinsic, N-type
SMD	surface mounted device
S4	special inspection level 4

# 10 Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP64LX v.6	20180704	Product data sheet	-	BAP64LX v.5
Modifications:	• changed I <sub>R</sub> co	value off V <sub>R</sub> at limiting value nditions at characteristics ayout of the data sheet	s	
BAP64LX v.5	20150512	Product data sheet	-	BAP64LX v.4
Modifications:	• AEC-Q101 qu	alified	'	
BAP64LX v.4	20140416	Product data sheet	-	BAP64LX v.3
BAP64LX v.3	20140211	Product data sheet	-	BAP64LX v.2
BAP64LX v.2	20130807	Product data sheet	-	BAP64LX v.1
BAP64LX v.1	20070629	Product data sheet	-	-

# 11 Legal information

### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
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